TAIWAN SEMICONDUCTOR

SF61G - SF68G

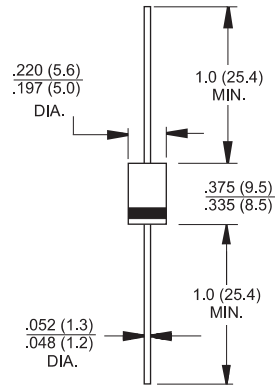
RoHS COMPLIANCE

6.0 AMPS. Glass Passivated Super Fast Rectifiers

DO-201AD

Features

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inventor, free wheeling, and polarity protection application



Dimensions in inches and (millimeters)

Mechanical Data

- ✧ Case: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.375",(9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 1.2 grams

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SF 61G	SF 62G	SF 63G	SF 64G	SF 65G	SF 66G	SF 67G	SF 68G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T_A = 55 °C	$I_{(AV)}$	6.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	150								A
Maximum Instantaneous Forward Voltage @ 6.0A	V_F	0.975				1.3		1.7		V
Maximum DC Reverse Current @ T_A=25 °C at Rated DC Blocking Voltage @ T_A=125 °C	I_R	5.0 100								uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35								nS
Typical Junction Capacitance (Note 2)	Cj	100				50				pF
Typical Thermal Resistance	$R_{\theta JA}$ $R_{\theta JL}$	40 5.0								°C/W
Operating Temperature Range	T_J	-65 to +150								°C
Storage Temperature Range	T_{STG}	-65 to +150								°C

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
3. Mount on Cu-Pad Size 16mm x 16mm on PCB.

RATINGS AND CHARACTERISTIC CURVES (SF61G THRU SF68G)

FIG.1- MAXIMUM AVERAGE FORWARD CURRENT DERATING

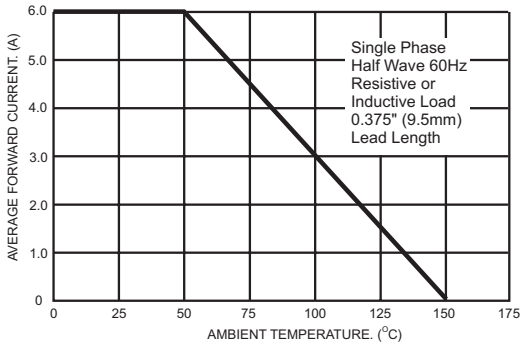


FIG.2- TYPICAL REVERSE CHARACTERISTICS

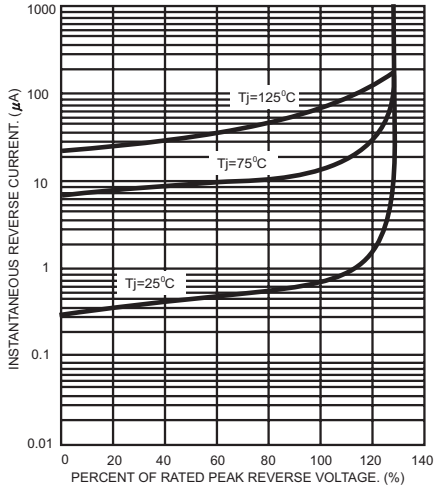


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

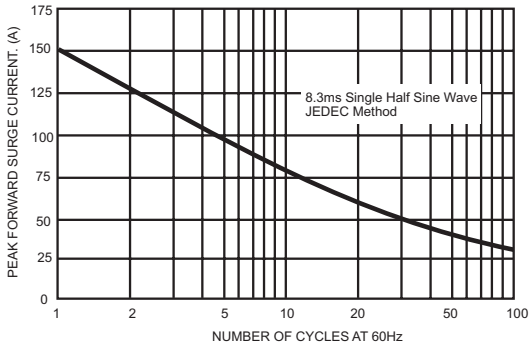


FIG.4- TYPICAL JUNCTION CAPACITANCE

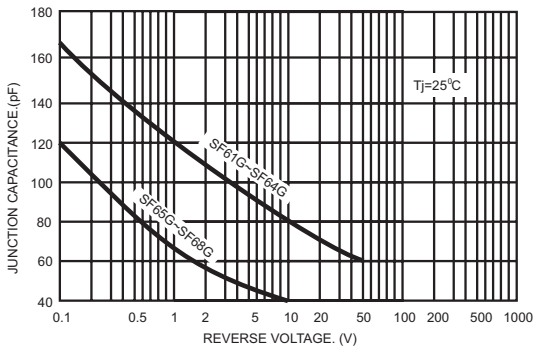


FIG.5- TYPICAL FORWARD CHARACTERISTICS

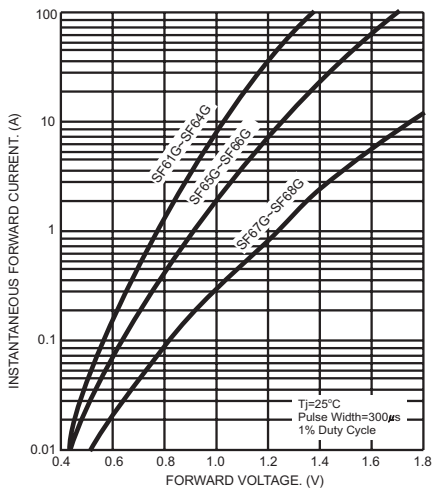
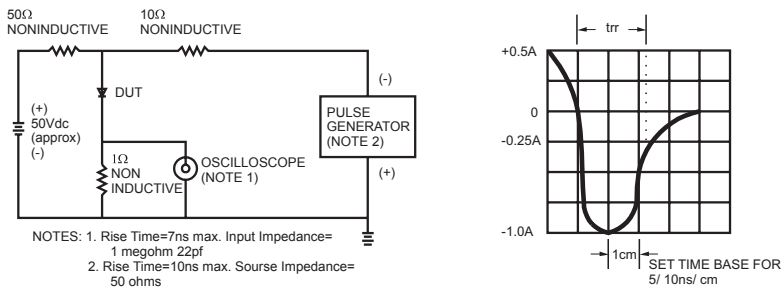


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES: 1. Rise Time=7ns max. Input Impedance= 1 megohm 22pf
2. Rise Time=10ns max. Sourse Impedance= 50 ohms

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Taiwan Semiconductor:

SF61G SF62G SF63G SF64G SF65G SF66G SF67G SF68G